

## FDB9403\_F085

### N-Channel Power Trench® MOSFET

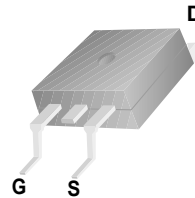
40V, 110A, 1.2mΩ

#### Features

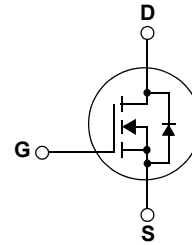
- Typ  $r_{DS(on)}$  = 1mΩ at  $V_{GS} = 10V$ ,  $I_D = 80A$
- Typ  $Q_{g(tot)}$  = 164nC at  $V_{GS} = 10V$ ,  $I_D = 80A$
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

#### Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems



TO-263AB  
FDB SERIES



#### MOSFET Maximum Ratings $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Rated	Units
$V_{DSS}$	Drain to Source Voltage		40	V
$V_{GS}$	Gate to Source Voltage		±20	V
$I_D$	Drain Current - Continuous ( $V_{GS}=10$ ) (Note 1)	$T_C = 25^\circ\text{C}$	110	A
	Pulsed Drain Current	$T_C = 25^\circ\text{C}$	See Figure4	
$E_{AS}$	Single Pulse Avalanche Energy	(Note 2)	968	mJ
$P_D$	Power Dissipation		333	W
	Derate above $25^\circ\text{C}$		2.22	W/ $^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature		-55 to + 175	$^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance Junction to Case		0.45	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	43	$^\circ\text{C}/\text{W}$

#### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB9403	FDB9403_F085	TO-263AB	330mm	24mm	800 units

#### Notes:

1. Current is limited by bondwire configuration. Please see Fairchild AN 9757-1 for details on test method.
2. Starting  $T_J = 25^\circ\text{C}$ ,  $L = 0.47\text{mH}$ ,  $I_{AS} = 64A$ ,  $V_{DD} = 40V$  during inductor charging and  $V_{DD} = 0V$  during time in avalanche.
- 3:  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

## Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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### Off Characteristics

$B_{V_{DSS}}$	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}, V_{GS} = 0\text{V}$	40	-	-	V
$I_{DSS}$	Drain to Source Leakage Current	$V_{DS} = 40\text{V}, T_J = 25^\circ\text{C}$	-	-	1	$\mu\text{A}$
		$V_{GS} = 0\text{V}, T_J = 175^\circ\text{C}(\text{Note 4})$	-	-	1	mA
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}$	-	-	$\pm 100$	nA

### On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu\text{A}$	2.0	3.13	4.0	V
$r_{DS(on)}$	Drain to Source On Resistance	$I_D = 80\text{A}, T_J = 25^\circ\text{C}$	-	1.0	1.2	$\text{m}\Omega$
		$V_{GS} = 10\text{V}, T_J = 175^\circ\text{C}(\text{Note 4})$	-	1.63	1.96	$\text{m}\Omega$

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$	-	12700	-	pF
$C_{oss}$	Output Capacitance		-	3195	-	pF
$C_{riss}$	Reverse Transfer Capacitance		-	493	-	pF
$R_g$	Gate Resistance	$f = 1\text{MHz}$	-	2.9	-	$\Omega$
$Q_{g(ToT)}$	Total Gate Charge at 10V	$V_{GS} = 0$ to 10V	-	164	213	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0$ to 2V				
$Q_{gs}$	Gate to Source Gate Charge	$V_{DD} = 20\text{V}, I_D = 80\text{A}$	-	59	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge		-	25	-	nC

### Switching Characteristics

$t_{on}$	Turn-On Time	$V_{DD} = 20\text{V}, I_D = 80\text{A}, V_{GS} = 10\text{V}, R_{GS} = 1.5\Omega$	-	-	56	ns
$t_{d(on)}$	Turn-On Delay Time		-	16	-	ns
$t_r$	Rise Time		-	19.5	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	61	-	ns
$t_f$	Fall Time		-	46	-	ns
$t_{off}$	Turn-Off Time		-	-	171	ns

### Drain-Source Diode Characteristics

$V_{SD}$	Source to Drain Diode Voltage	$I_{SD} = 35\text{A}, V_{GS} = 0\text{V}$	-	-	0.85	V
		$I_{SD} = 15\text{A}, V_{GS} = 0\text{V}$	-	-	0.80	V
$T_{rr}$	Reverse Recovery Time	$I_F = 80\text{A}, dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	96	125	ns
$Q_{rr}$	Reverse Recovery Charge		-	149	194	nC

**Notes:**

4: The maximum value is specified by design at  $T_J = 175^\circ\text{C}$ . Product is not tested to this condition in production.

### Typical Characteristics

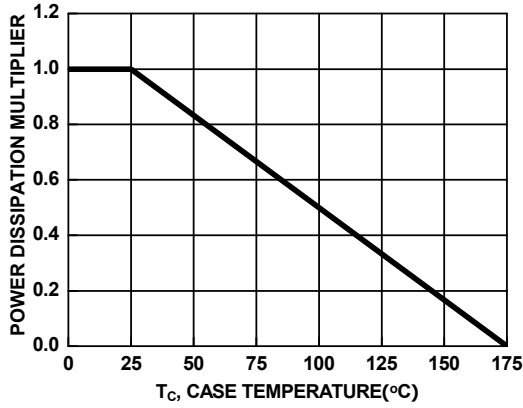
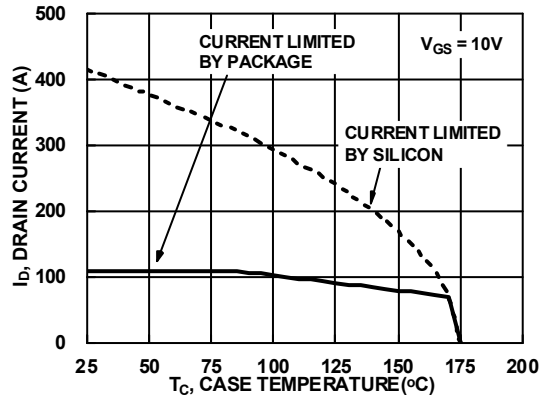


Figure 1. Normalized Power Dissipation vs Case Temperature



NOTE: Refer to Fairchild Application Notes AN9757

Figure 2. Maximum Continuous Drain Current vs Case Temperature

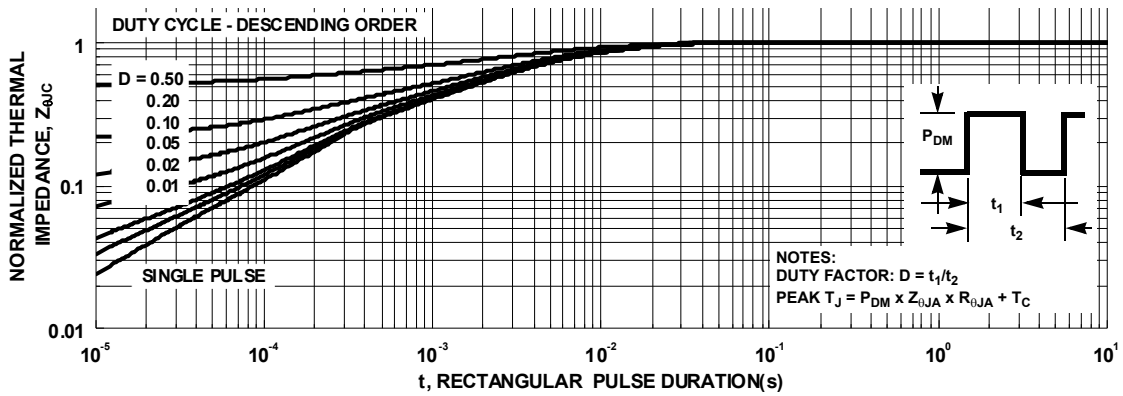


Figure 3. Normalized Maximum Transient Thermal Impedance

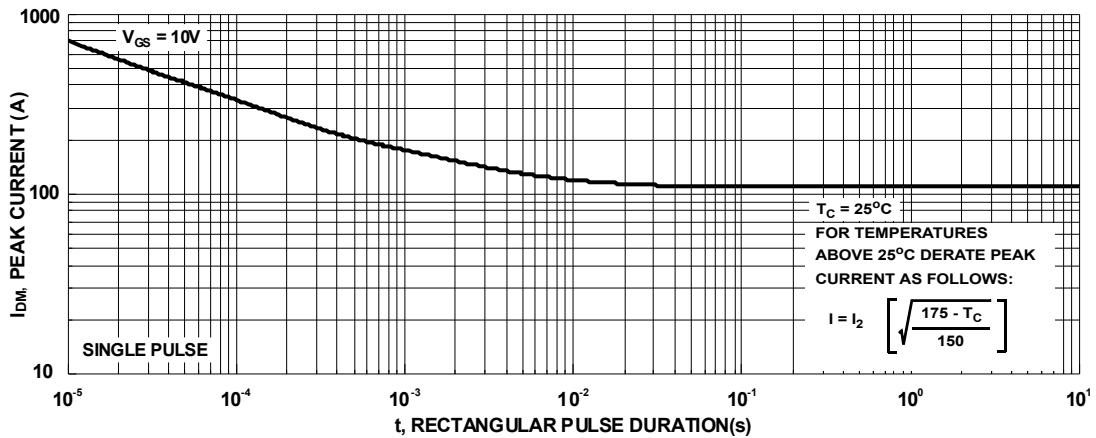


Figure 4. Peak Current Capability

### Typical Characteristics

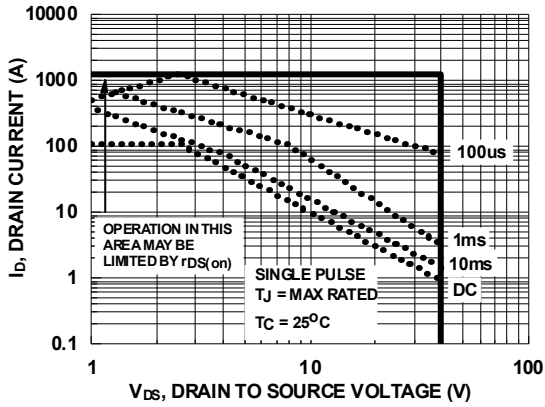
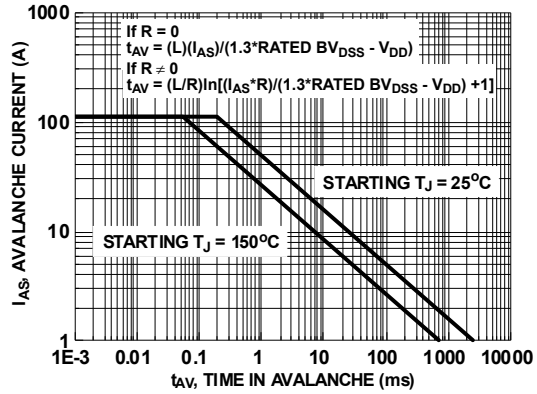


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching Capability

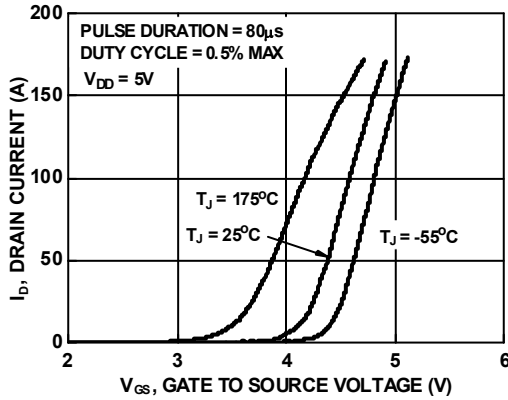


Figure 7. Transfer Characteristics

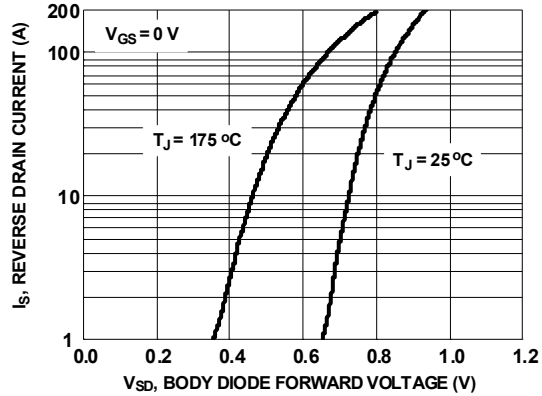


Figure 8. Forward Diode Characteristics

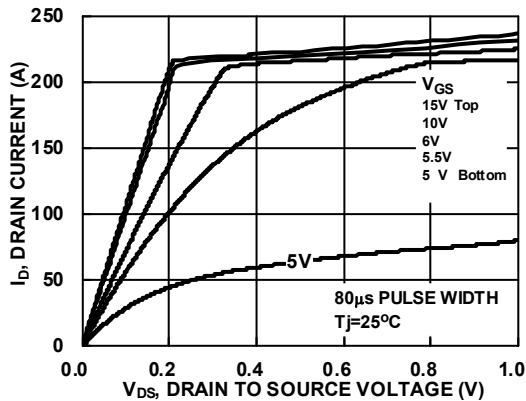


Figure 9. Saturation Characteristics

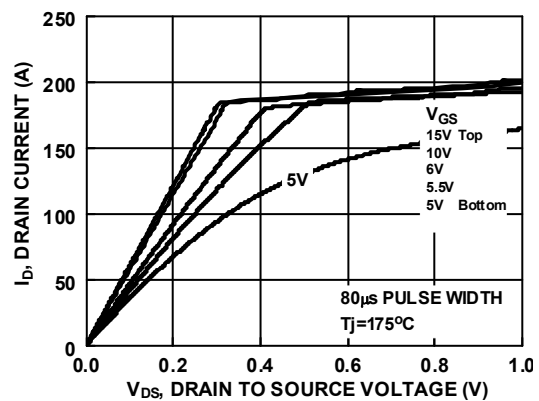


Figure 10. Saturation Characteristics

## Typical Characteristics

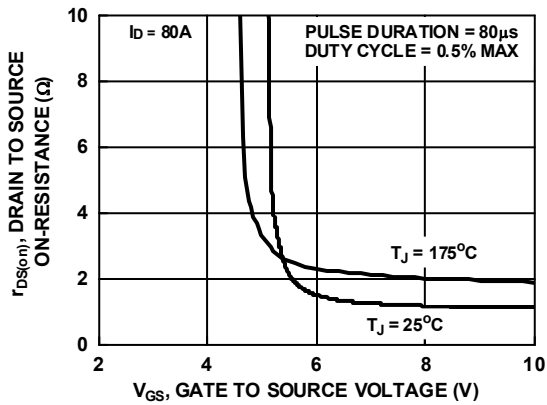


Figure 11. Rdson vs Gate Voltage

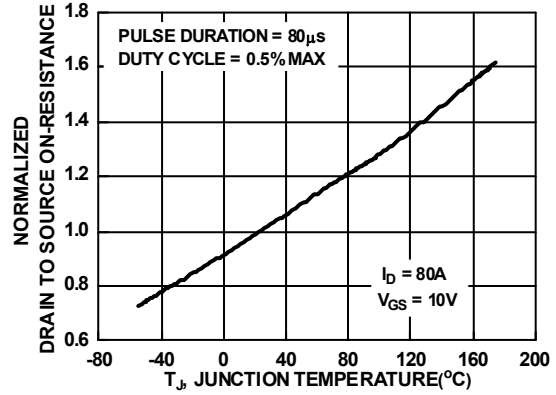


Figure 12. Normalized Rdson vs Junction Temperature

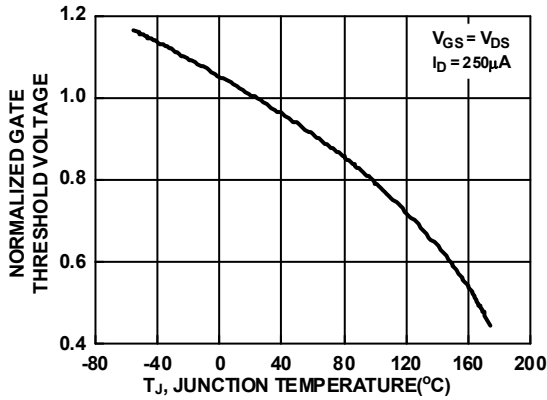


Figure 13. Normalized Gate Threshold Voltage vs Temperature

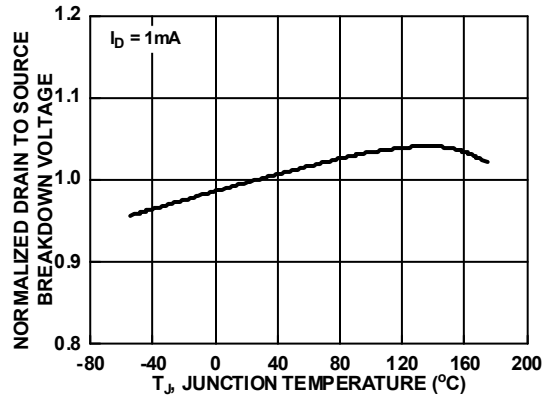


Figure 14. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

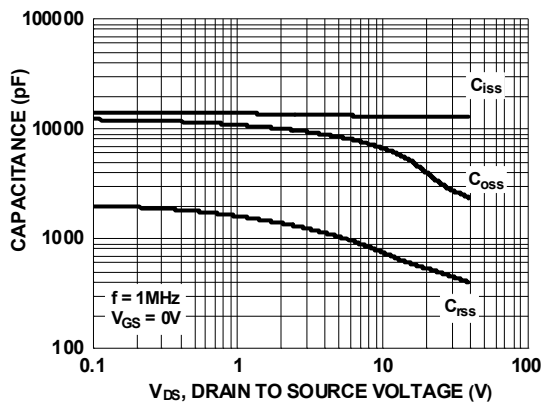


Figure 15. Capacitance vs Drain to Source Voltage

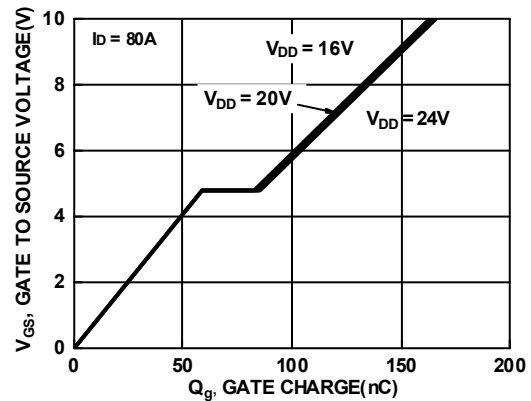


Figure 16. Gate Charge vs Gate to Source Voltage



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